

OPEN

Towards visible light driven photoelectrocatalysis for water treatment: Application of a FTO/BiVO₄/Ag₂S heterojunction anode for the removal of emerging pharmaceutical pollutants

Benjamin O. Orimolade¹ & Omotayo A. Arotiba^{1,2*}

Pharmaceuticals have been classified as emerging water pollutants which are recalcitrant in nature. In the quest to find a suitable technique in removing them from contaminated water, photoelectrocatalytic oxidation method has attracted much attention in recent years. This report examined the feasibility of degrading ciprofloxacin and sulfamethoxazole through photoelectrocatalytic oxidation using FTO-BiVO₄/Ag₂S with p-n heterojunction as anode. BiVO₄/Ag₂S was prepared through electrodeposition and successive ionic layer adsorption/reaction on FTO glass. Structural and morphological studies using XRD, SEM, EDS and diffusive reflectance UV-Vis confirmed the successful construction of p-n heterojunction of BiVO₄/Ag₂S. Electrochemical techniques were used to investigate enhanced charge separation in the binary electrode. The FTO-BiVO₄/Ag₂S electrode exhibited the highest photocurrent response (1.194 mA/cm²) and longest electron lifetime (0.40 ms) than both pristine BiVO₄ and Ag₂S electrodes which confirmed the reduction in recombination of charge carriers in the electrode. Upon application of the prepared FTO-BiVO₄/Ag₂S in photoelectrocatalytic removal of ciprofloxacin and sulfamethoxazole, percentage removal of 80% and 86% were achieved respectively with a low bias potential of 1.2V (vs Ag/AgCl) within 120 min. The electrode possesses good stability and reusability. The results obtained revealed BiVO₄/Ag₂S as a suitable photoanode for removing recalcitrant pharmaceutical molecules in water.

Water pollution is a global challenge with a lot of negative environmental and health implications. Pollution has the likelihood of increasing owing to increase in industrial activities, improper discharge of household effluents, inefficient wastewater treatment of polluted water and so on. Recalcitrant organic compounds such as pharmaceuticals constitute a major class of emerging water pollutants. Pharmaceuticals, particularly antibiotics have been reportedly found in wastewater and groundwater¹. When such antibiotics are present in water, they pose serious danger to aquatic organisms and continuous consumption of such water by human can also result in chronic health issues such as the development of strains of bacteria that are resistant to antibiotics². Over the past decades much attention has been directed to developing water treatment methods that are efficient and environmentally friendly since methods based on conventional wastewater treatments often lead to secondary pollutions and incomplete removal of target pollutants in water^{3,4}. A recent approach for removing these recalcitrant organics from wastewater is photoelectrocatalytic (PEC) oxidation using suitable semiconducting materials as photoanodes^{5,6}.

Photoelectrocatalytic oxidation is an environmentally friendly approach that uses both photon and electric energy to generate powerful oxidants (such as hydroxyl radical) that attack and destroy organic molecules that are present in aqueous solution. When this technique is used to treat water contaminated with recalcitrant

¹Department of Chemical Sciences, University of Johannesburg, Johannesburg, South Africa. ²Centre for Nanomaterials Science Research, University of Johannesburg, Johannesburg, South Africa. *email: oarotiba@uj.ac.za

organic molecules such as pharmaceuticals, total mineralization to water and carbon dioxide can be achieved over a period of time or the molecules can be broken down to non-toxic organic molecules within a short period of time⁷. Another interesting advantage of this approach is that the use of bias potential results in significant reduction in the challenge of rapid and spontaneous recombination of charge carriers that is peculiar to photocatalysis⁸. Titanium dioxide (TiO₂) and zinc oxide (ZnO) remained the most applied semiconducting photocatalyst as anodic material for photoelectrocatalytic degradation of organics^{9–11}. Owing to the wide band gaps of TiO₂ (3.2 eV) and ZnO (3.5 eV), they perform best with the application of UV light but the UV region accounts for less than 5% of the solar spectrum¹². Therefore, other sources of UV light which are expensive are often needed when using TiO₂ and ZnO. In order to cut down the cost associated with the operation of photoelectrocatalytic degradation process, solar light has been considered as a source of photon energy but this requires that the anodic material be made up of visible light active photocatalyst. In this line, semiconductor photocatalysts such as WO₃¹³, CuI¹⁴, Ag₃VO₄¹⁵, Cu₂O¹⁶, BiVO₄^{17,18}, Fe₂O₃¹⁹, CuS²⁰, Ag₃PO₄²¹, WS₂²² and C₃N₄^{23,24} have been studied for PEC processes.

In the large pool of visible light active semiconductors, monoclinic sheelite bismuth vanadate (m-BiVO₄) has proven to be a choice material for PEC applications. As an n-type semiconductor, with narrow band gap (2.4 eV), BiVO₄ possesses impressive photocatalytic activity under the application of solar light, it is non-toxic and has good stability. m-BiVO₄ has been employed as anodic material for the degradation of pollutants in wastewater⁶. It has also found application in PEC water splitting for hydrogen evolution²⁵. Unfortunately, the use of unmodified BiVO₄ is faced with the problem of poor transport of charge carriers as well as relatively fast recombination of photo-excited charge carriers. Over the years, researchers have employed several techniques to counter this problem which include doping with metallic and/or non-metallic impurities, preparation nanosized BiVO₄ with well-defined morphology, loading of catalyst and formation of heterojunctions with other semiconductors^{26,27}. Among these approaches, the formation of heterojunction with other semiconductors have proven to be the most effective.

Basically, heterojunction is formed when two semiconductors of unequal band gap combined in such a way that it results in band alignment²⁸. It has been observed that the formation of heterojunctions between p-type and n-type semiconductor can improve PEC activity through improved light harvesting, effective separation of photogenerated electron-hole pairs and thus increased the lifespan of the charge carriers. For instance, Soltani *et al.*²⁹, prepared BiFeO₃/BiVO₄ with p-n heterojunction through facile ultrasonic/hydrothermal route and they observed improved charge separation in the composite as shown in the current density of 0.23 mA/cm⁻² achieved on BiFeO₃/BiVO₄ which was three times higher than that of pristine BiVO₄. Additionally, higher percentage degradation of tetracycline was reported with the application of the prepared BiFeO₃/BiVO₄ p-n heterostructure. Likewise, similar observations have been demonstrated in other BiVO₄ based p-n heterostructures such as Cu₂O/BiVO₄³⁰, BiVO₄/MnO₂³¹, BiVO₄/CeVO₄³², WO₃/BiVO₄³³, CdS/BiVO₄³⁴, Fe₂O₃/BiVO₄³⁵, BiVO₄/ZnO³⁶, BiVO₄/NiO³⁷, β-AgVO₃/BiVO₄³⁸ and BiVO₄/Ag₃PO₄³⁹.

The selection of an appropriate p-type semiconductor is a critical step to achieve p-n heterojunction of BiVO₄ with improved performance. Recently, attention has been given to silver sulfide (Ag₂S) as a suitable semiconductor to form p-n heterojunction with BiVO₄. As a chalcogenide based p-type semiconductor, Ag₂S has good optical properties and photocatalytic activity owing to its small band gap (between 0.9–1.1 eV)⁴⁰. BiVO₄/Ag₂S p-n heterostructure prepared through hydrothermal routes have shown enhanced photocatalytic performance for the degradation of dyes and pharmaceuticals⁴¹. Guan *et al.*⁴², have also demonstrated the photoelectrochemical performance of BiVO₄/Ag₂S in water splitting and achieved a high photocurrent density of 1.91 mA/cm². To the best of our knowledge, the performance of BiVO₄/Ag₂S in photoelectrochemical oxidation of pharmaceuticals in aqueous solution have not been reported.

Herein, we report for the first time the photoelectrocatalytic degradation of pharmaceuticals in water using a p-n heterostructure of BiVO₄/Ag₂S prepared on FTO glass as anode. The BiVO₄/Ag₂S photoanode with improved PEC performance was prepared on FTO glass using two-step electrodeposition and successive ionic layer adsorption/reaction (SILAR) methods. The optical property of the electrode was studied using UV diffusive reflectance spectroscopy (UV-DRS) while structural and morphological studies were carried out with XRD, SEM and EDS. Chronoamperometry and linear sweep voltammetry were used to confirm improved photocurrent response of the material. Electrochemical impedance spectroscopy and Mott Schottky plot were also used to establish the formation of heterojunction between the two semiconductors. Ciprofloxacin and sulfamethoxazole were selected as pollutant of interest for the photoelectrocatalytic degradation experiments.

Experimental

Materials and reagents. All the chemicals used were purchased from Sigma Aldrich (South Africa). These include bismuth nitrate pentahydrate (Bi(NO₃)₃·5H₂O), potassium iodide, vanadylacetylacetonate, silver nitrate, sodium sulfide, sodium hydroxide pellets, p-benzoquinone, sodium sulfate, potassium hexacyanoferrate (II), potassium hexacyanoferrate (III), ciprofloxacin and sulfamethoxazole.

Preparation of BiVO₄/Ag₂S photoanodes. The binary photoanode with p-n heterojunction was fabricated through a two-step electrodeposition and Successive Ion Layer Adsorption/Reaction methods. First, BiVO₄ were electrodeposited on a FTO glass (5 cm × 1.3 cm × 0.22 cm, surface resistivity of ~7 Ω/sq) using a modified previously documented electrodeposition technique^{34,43}. Summarily, from a well sonicated precursor solution containing 0.49 g Bi(NO₃)₃·5H₂O, 1.66 g KI in 25 mL and 0.23 M p-benzoquinone maintained at pH 4.3, films of BiOI were first potentiostatically electrodeposited onto a clean FTO glass at -0.13 V for 720 s. FTO glass, platinum wire and Ag/AgCl (3.0 M KCl) electrode were employed as the working electrode, counter electrode and reference electrode respectively. After rinsing the obtained BiOI electrode with water several times and drying at room temperature, 100 μL of 0.20 M vanadylacetylacetonate (dissolved in DMSO) was drop-cast evenly onto

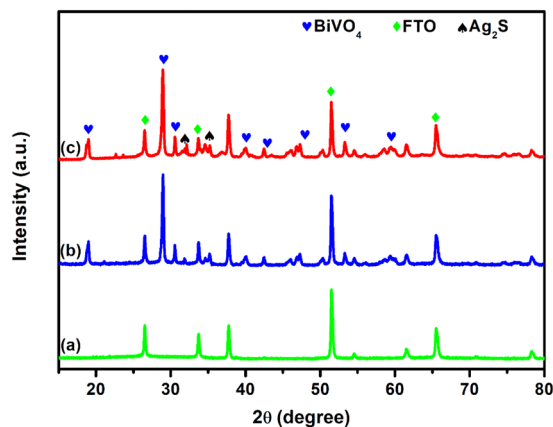


Figure 1. XRD patterns of (a) FTO, (b) FTO/BiVO₄ and FTO/BiVO₄/Ag₂S.

the BiOI electrode. The electrode was subsequently placed in a furnace at 420 °C for 1 h. Finally, excess V₂O₅ was washed off from the electrode by soaking it in 1.0 M NaOH solution for 40 min. The resulting BiVO₄/FTO electrode was thoroughly washed with deionized water and dried at room temperature. In order to obtain BiVO₄/Ag₂S electrode, the prepared FTO/BiVO₄ was dipped in a 0.3 M AgNO₃ solution for 10 s and followed by immersion in 0.3 M Na₂S for 10 s. The cycle was repeated ten times and the obtained electrode was rinsed with deionized water and air dried at room temperature for 24 h.

Structural and morphology characterisation of the prepared electrodes. X-ray diffractometer (Rigaku Ultima IV, Japan) using Cu K α radiation ($k = 0.15406$) with K-beta filter at 30 mA and 40 kV was used to identify the phase, degree of crystallinity and purity of the prepared semiconductor photoanodes. TESCAN Vega 3 (Czech Republic) scanning electron microscope was employed to determine surface morphology of the material. Energy-dispersive spectrometer (EDS) attached to the SEM instrument was used to confirm the presence of expected elements in the prepared materials in the appropriate ratio. The light absorption properties of the materials were analyzed using UV/Visible-Diffuse Reflectance Spectroscopy. A similar characterisation methods has been previously reported⁴³.

Electrochemical and photoelectrochemical experiments. The electrochemical and photoelectrochemical experimental protocols are similar to that described in our previous reports^{8,43}. Photocurrent measurements, linear sweep voltammetry (LSV) and electrochemical impedance spectroscopy (EIS) were performed on an Autolab PGSTAT204 (Netherlands) potentiostat/galvanostat. The working electrodes were the prepared BiVO₄, Ag₂S and BiVO₄/Ag₂S electrodes. Platinum sheet with equal dimension as the FTO glass was employed as counter electrode while the reference electrode was Ag/AgCl (3.0 M KCl). Chronoamperometry and LSV were carried out in a 0.1 M Na₂SO₄ solution. EIS was done in a 5 mM solution of [Fe(CN)₆]^{3-/4-} (prepared in a 0.1 M KCl solution). Data for Mott Schottky plots were obtained under dark condition at room temperature. For photoelectrochemical experiments, a solar simulator equipped with a 100 W xenon lamp was used as the light source. The prepared electrode was fixed vertically facing the incident light of the simulator and the distance between the photoelectrochemical cell and the light source was 10 cm and the glass were illuminated from the rear. The experiments were performed in a 70 mL capacity reactor made of quartz glass. For the degradation experiments, the working solution was 50 mL solution of 0.1 M Na₂SO₄ (supporting electrolyte) and 10 mgL⁻¹ of the pharmaceuticals. Aliquots of the solution taken from the reactor at predefined time intervals using a disposable syringe were analyzed using UV-Visible spectrophotometer to obtain the concentration decay pattern. The total organic carbon was also measured using TOC analyser (Teledyne Tekmar TOC fusion). The applied bias potential was optimized by performing the PEC experiments at different bias potential.

Results and discussion

Structural and morphology characterization of the electrodes. The X-ray diffractograms of the prepared photoanodes are presented in Fig. 1. All the peaks correspond to those of monoclinic scheelite BiVO₄ (JCPDS no. 75-1866) in the XRD pattern of the BiVO₄. The main peaks at 18.8°, 28.73°, 30.64°, 34.01°, 35.06°, 39.95° and 42.35° can be indexed as (110, 011), (121), (040), (200), (002), (211) and (150) crystal planes respectively⁴⁴. In the XRD pattern of BiVO₄/Ag₂S, the diffraction peaks of Ag₂S are not pronounced and well visible which could suggest that the particles are well dispersed on the surface of the BiVO₄ or probably due to relatively lower content and low crystallinity of Ag₂S loading⁴⁵. Nonetheless, the presence of Ag₂S in the sample is evident in the peaks at 32° and 35° which appeared to be superimposed on those of BiVO₄ and therefore changing their intensities⁴⁶. Expectedly, all the characteristic peaks BiVO₄ were still observed in the XRD pattern of the BiVO₄/Ag₂S electrode. In order to further confirm the presence of Ag₂S on the binary electrode, other morphological studies were carried out.

The surface morphology of the photoanodes prepared on FTO glass are shown in Fig. 2(a-c). The prepared Ag₂S appears as fine particles dispersed on the FTO glass (2a) while the particles of BiVO₄ are agglomerated on the FTO glass forming film like structure (2b). The incorporation of Ag₂S particles onto the BiVO₄ on FTO glass

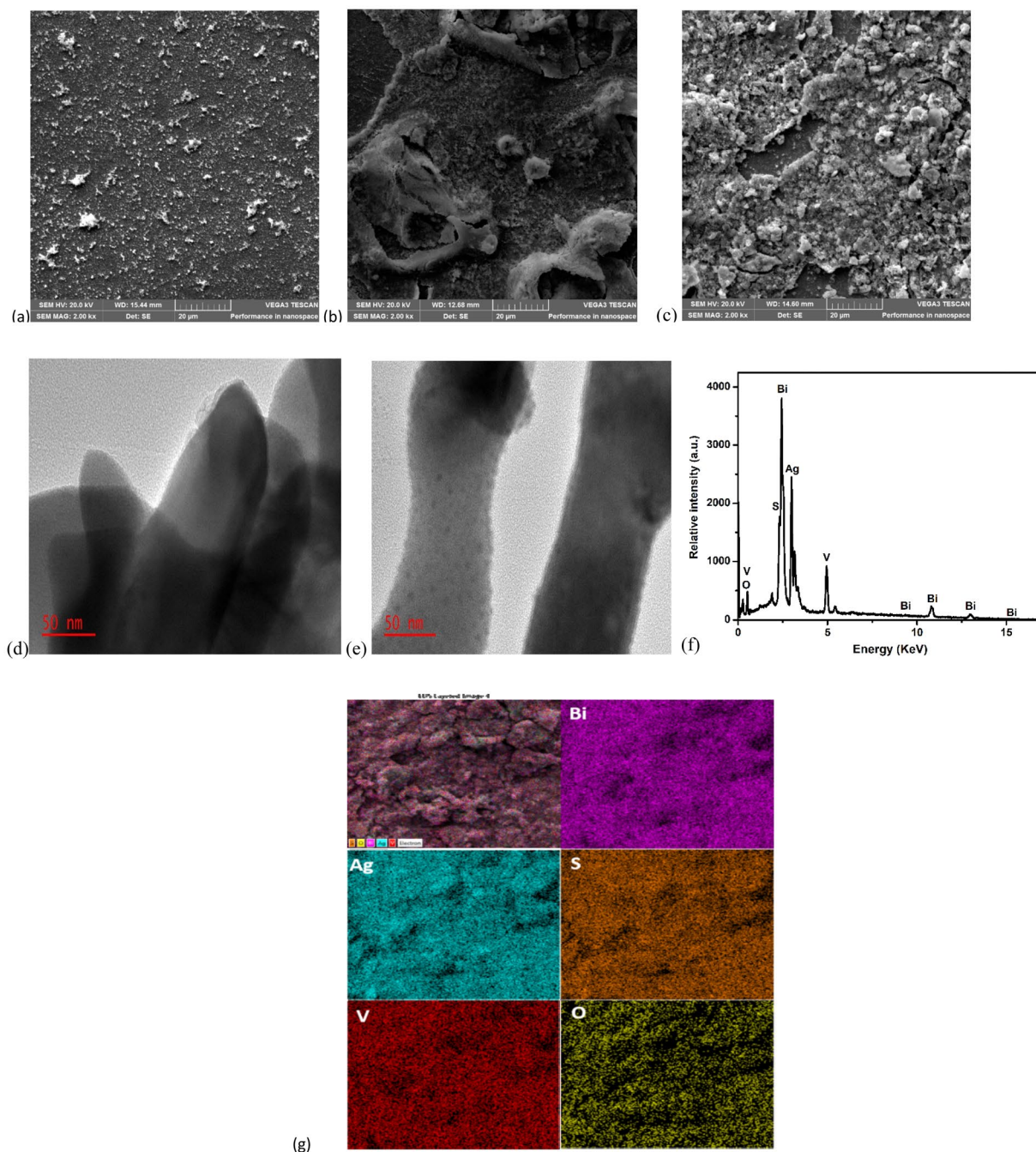


Figure 2. SEM images of (a) FTO-Ag₂S; (b) FTO-BiVO₄; (c) FTO-BiVO₄/Ag₂S; HR-TEM images of (d) BiVO₄; (e) BiVO₄/Ag₂S; (f) EDS spectrum of FTO-BiVO₄/Ag₂S and (g) EDS elemental mapping of FTO-BiVO₄/Ag₂S electrode.

resulted in agglomerated globules with openings which could serve as active sites for capturing of target analytes as shown the SEM image of FTO-BiVO₄/Ag₂S (Fig. 2c) and this further established that Ag₂S were successfully coupled with the electrodeposited BiVO₄. HR-TEM was further used to evaluate the nanostructure and heterostructure interface between BiVO₄ and Ag₂S in the BiVO₄/Ag₂S composite and the from the results it can be seen that BiVO₄ materials appeared as nanorods of different sizes (Fig. 2d) while Ag₂S were nanoparticles which were well dispersed on the surface of BiVO₄ nanorods (Fig. 2e) suggesting the successful formation of appropriate heterostructure interface. As shown in Fig. 2f, the EDS spectrum revealed that only Bi, V, O, Ag and S were present in the composite electrode suggesting that the material is reasonably pure since no unwanted element was observed in the spectrum. Additionally, the percentage composition of each element obtained from the result also agreed with theoretical calculation of the elemental composition of BiVO₄/Ag₂S composite. It is also interesting to note that distribution of the elements on the electrode surface is uniform as revealed in the EDS mapping (Fig. 2g) and this further confirmed the evenly spread of Ag₂S particles on the electrodeposited BiVO₄.

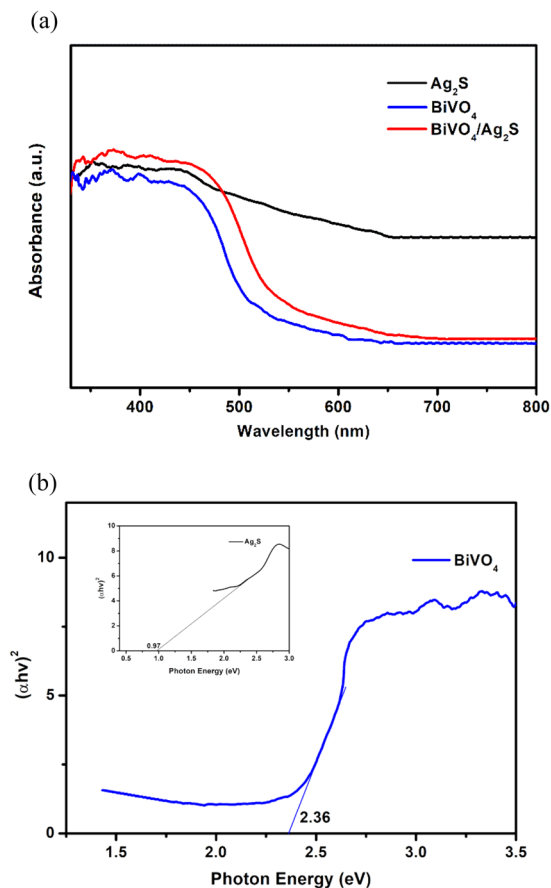


Figure 3. (a) UV-Visible diffuse reflectance spectra and (b) the energy band gap edges of Ag₂S, BiVO₄ and BiVO₄/Ag₂S electrodes.

Optical properties of the photoanodes. The optical properties of the prepared Ag₂S, BiVO₄ and BiVO₄/Ag₂S electrodes were studied using UV-Visible diffuse reflectance spectroscopy and the results are shown in Fig. 3a. All the electrodes absorb photons in the visible light region and the absorption edges can be traced to 540 nm and 620 nm for BiVO₄ and BiVO₄/Ag₂S respectively while the absorption edge of Ag₂S tends towards the near infrared. The shift of the absorption edge of BiVO₄/Ag₂S and increase in absorption can rightly be attributed to the enhancement of BiVO₄ optical ability through the addition of Ag₂S. In order to determine the band gap energy of the two semiconductors, the data obtained from the UV-DRS analyses were fit into Tauc equation which established that the band gap energy of a semiconductor can be determined using Eq. (1).

$$\alpha h\nu = A(h\nu - E_g)^{n/2} \quad (1)$$

where α , h , A , E_g and ν are the absorption coefficient, Planck's constant, constant, band gap energy and incident light frequency respectively; 'n' is a constant that depends solely on the optical transition characteristics of the semiconductors under consideration. For direct transition semiconductors the value of 'n' is 1⁴⁷. Since both BiVO₄ and Ag₂S are direct semiconductors, a plot of $(\alpha h\nu)^2$ against $h\nu$ was made from which the value of E_g for BiVO₄ and Ag₂S were estimated to be 2.36 eV and 0.97 eV respectively (Fig. 3b). The values for the band gap energies obtained for both BiVO₄ and Ag₂S are in agreement with previously reported values for the semiconductors^{48,49}. These results further confirm the successful preparation of visible light active semiconductor photocatalysts. The improved photoabsorption in BiVO₄/Ag₂S suggested enhanced charge separation through band alignment when BiVO₄ and Ag₂S combined together and this was further established through series of photoelectrochemical experiments.

Electrochemical and photoelectrochemical analysis. Linear sweep voltammetry (LSV) of the photoanodes were carried out in a solution of 0.1 M Na₂SO₄ (pH 7) at a scan rate of 20 mVs⁻¹. The linear voltammograms (Fig. 4a) were recorded in both the presence and absence of visible light illumination. All the electrodes showed higher current responses with illumination than without illumination which could be attributed to that fact that when the materials were irradiated, there is instantaneous excitation of electrons from the valence band to the conduction band and this enhanced better conductivity. Ag₂S shows improved responses at 0.28 V and 0.85 V while BiVO₄ show a continuous increase in photocurrent response with increase in potential. Interestingly, though the binary electrode of BiVO₄/Ag₂S showed the characteristics features of both the voltammogram

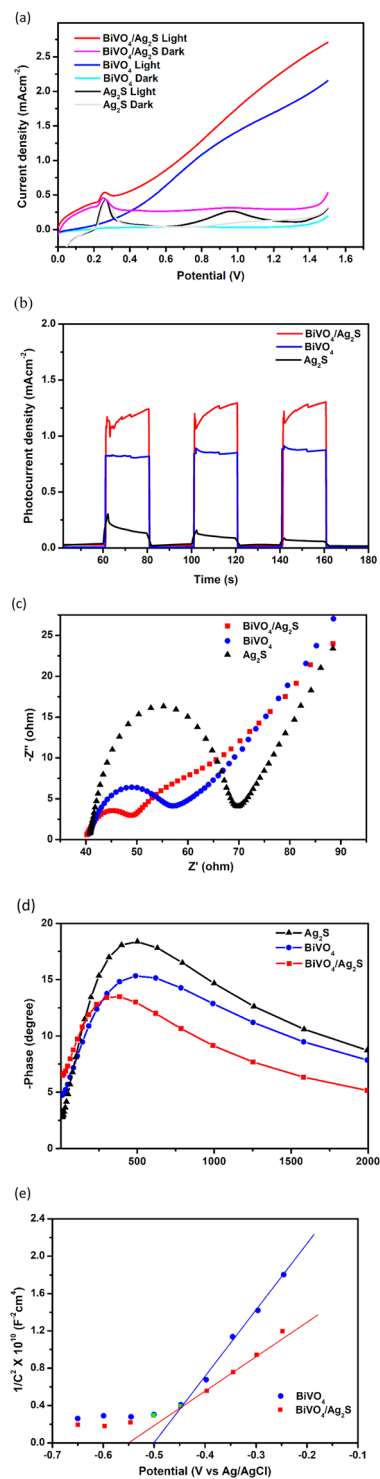


Figure 4. (a) Linear sweep voltammogram at 20 mVs^{-1} ; (b) photocurrent response in $0.1 \text{ M Na}_2\text{SO}_4$; (c) Nyquist EIS plot; (d) Bode plot and (e) Mott Schottky plot for Ag_2S , BiVO_4 and $\text{BiVO}_4/\text{Ag}_2\text{S}$ photoanodes in $5 \text{ mM } [\text{Fe}(\text{CN})_6]^{3-/4-}$ in 0.1 M KCl (pH 7).

obtained with Ag_2S and BiVO_4 (Fig. 4a) its overall increase in photocurrent response with increase in potential was higher than both the pristine electrode suggesting a good improvement in charge separation resulting in higher light responsiveness through the construction heterointerface. The anodic peak at ca 250 mV (Fig. 4a) is due to the oxidation of silver. This peak occurs only in Ag containing electrodes and thus a further confirmation of the presence of Ag_2S in the heterojunction electrode $\text{BiVO}_4/\text{Ag}_2\text{S}$.

It has been also been established that there is a linear correlation between the transient photocurrent of a semiconductor and the charge separation process taking place within the material¹³. Therefore, with applied

external potential of +0.8 V (selected based on the LSV performance of the electrodes), the transient photocurrent responses of the electrodes were recorded using chronoamperometry method (Fig. 4b). As expected, the highest photocurrent (1.194 mA/cm^{-2}) was attained with $\text{BiVO}_4/\text{Ag}_2\text{S}$ electrode which was significantly higher than that of pristine BiVO_4 (0.802 mA/cm^{-2}) and almost ten times greater than that of Ag_2S (0.165 mA/cm^{-2}). Therefore, it was clear that the construction of p-n heterojunction between BiVO_4 and Ag_2S promotes charge transfer between the interfaces of the two semiconductors which greatly inhibit the rapid recombination of photogenerated electron – hole pairs in the $\text{BiVO}_4/\text{Ag}_2\text{S}$ electrode.

The results obtained with electrochemical impedance spectroscopy further corroborate the improved performance of $\text{BiVO}_4/\text{Ag}_2\text{S}$ heterojunction through synergistic effect of both BiVO_4 and Ag_2S . The experiments were performed in an electrolytic solution of $5 \text{ mM } [\text{Fe}(\text{CN})_6]^{3-/4-}$ in 0.1 M KCl (pH 7) with external application of $+0.2 \text{ V}$. The obtained Nyquist plots for the fabricated photoanodes are displayed in Fig. 4c. For all the electrodes single characteristic semicircles were obtained in the EIS spectra which signifies the charge transfer process happening at the solution-electrode interface. The size of the semi-circular arc in the spectra is a function of the charge-transfer resistance (R_{ct}) at the interface of the heterojunction and studies have shown that the smaller the arc radius the better the charge transfer efficiency^{50,51}. Accordingly, the lowest R_{ct} was obtained from the Nyquist plot of $\text{BiVO}_4/\text{Ag}_2\text{S}$. This further affirmed that the formation of heterojunction between BiVO_4 and Ag_2S resulted in better charge mobility and lowered rate of instantaneous recombination of photogenerated electron-hole pairs. Furthermore, the impedance data were analyzed with a bode phase angle plot (Fig. 4d) to determine the electrons lifetime and charge transfer resistance in the $\text{BiVO}_4/\text{Ag}_2\text{S}$ electrode. As shown in Fig. 4d, the maximum phase angle of the heterojunction electrode shifts to lowest frequency as compared to both Ag_2S and BiVO_4 . This confirms the rapid electron transport process happening in the heterojunction. The life time of electrons is related to the frequency as given in Eq. (2)⁵².

$$\tau_e = 1/2\pi f_{max} \quad (2)$$

where f_{max} is the frequency at the maximum phase angle the bode plot. Using Eq. (2), the electron lifetime of $\text{BiVO}_4/\text{Ag}_2\text{S}$ was calculated to be 0.40 ms which was longer than those of BiVO_4 (0.32 ms) and Ag_2S (0.31 ms). This value of life time calculated further confirms that the fabrication of the heterojunction helped in minimizing rapid recombination of electron – hole pairs in the two semiconductors through a fast charge transfer process⁵³.

The flat band potential (E_{FB}) and charge carrier density (N_D) of a semiconductor can also be used as a measure of improved charge separation in semiconductor – semiconductor heterojunction interfaces = These values can be obtained from potential scan measurements and fitting of data to obtain Mott Schottky plot. Mott Schottky equation is given in Eq. 3.

$$1/C^2 = 2/(e\epsilon\epsilon_0N_D) \cdot (E_{app} - E_{FB} - kT/e) \quad (3)$$

C , e , ϵ , ϵ_0 , E_{app} , T , N_D , E_{FB} and k represent the capacitance at the semiconductor/electrolyte interface (Fcm^{-2}), elementary charge ($1.60 \times 10^{-19} \text{ C}$), dielectric constant (68 for BiVO_4 ⁵⁴), permittivity of vacuum, external applied potential, absolute temperature, donor density, flat band potential and Boltzmann constant respectively.

From Eq. (3), a plot of $1/C^2$ against E_{app} was constructed and Donor density (N_D) was calculated from the slope while the approximately value of flat band potential was extrapolated from the intercept (Fig. 4e). As an n-type semiconductor, the MS plot of BiVO_4 gave a positive slope value. A negative shift in the flat band potential from -0.512 V in BiVO_4 to -0.548 V in $\text{BiVO}_4/\text{Ag}_2\text{S}$ was also observed and this suggested that the rate of rapid recombination of charge carriers in the constructed $\text{BiVO}_4/\text{Ag}_2\text{S}$ heterojunction was greatly reduced. This observation was further justified the carrier density of $\text{BiVO}_4/\text{Ag}_2\text{S}$ ($3.87 \times 10^{22} \text{ cm}^{-3}$) which was significantly larger than that of pristine BiVO_4 ($8.07 \times 10^{21} \text{ cm}^{-3}$).

Photoelectrocatalytic degradation of pollutants. The photoelectrocatalytic degradation of organics on the prepared $\text{BiVO}_4/\text{Ag}_2\text{S}$ electrode was evaluated by using ciprofloxacin and sulfamethoxazole as target water contaminants. The degradation was achieved with an applied bias potential of 1.2 V , pH 7 and simulated sunlight was used as light source. The degradation processes of the pharmaceuticals were followed using UV-Visible spectrophotometer and evidence of reduction in the concentrations of ciprofloxacin and sulfamethoxazole was seen by the decrease in the intensity of the peaks at 276 nm and 265 nm for ciprofloxacin and sulfamethoxazole respectively. Within 120 min, a percentage removal of 80% and 86% for ciprofloxacin and sulfamethoxazole was achieved (Fig. 5a,b). The breaking down of ciprofloxacin molecules was further confirmed through the percentage total organic carbon removal (TOC) which was 69%. In the absence of light, the percentage anodic electrochemical degradation of ciprofloxacin and sulfamethoxazole were 59% and 61% respectively while percentage degradation achieved with photocatalysis alone was 35% and 40% respectively. The highest degradation achieved with photoelectrocatalytic degradation showed that the application of bias potential in conjunction with photocatalysis facilitated the breaking down of the organic molecules as the bias potential helps in driving away photoexcited electrons from the surface of the photoanode and thereby reducing the occurrence of recombination of the electron – hole pairs.

The kinetics studies also revealed that the degradation processes of both ciprofloxacin and sulfamethoxazole were fastest with the application of photoelectrocatalytic oxidation (Figs. S1 and S2). It is also interesting to note that the degradation of sulfamethoxazole on the $\text{BiVO}_4/\text{Ag}_2\text{S}$ electrode appeared to be more favourable than that of ciprofloxacin as evident with the higher percentage degradation (86%) and supported with the apparent rate constant (0.0147 min^{-1}) which was higher than that of ciprofloxacin (80% and 0.0137 min^{-1}). This could be attributed partly to the larger molecular mass and more complex structure of ciprofloxacin.

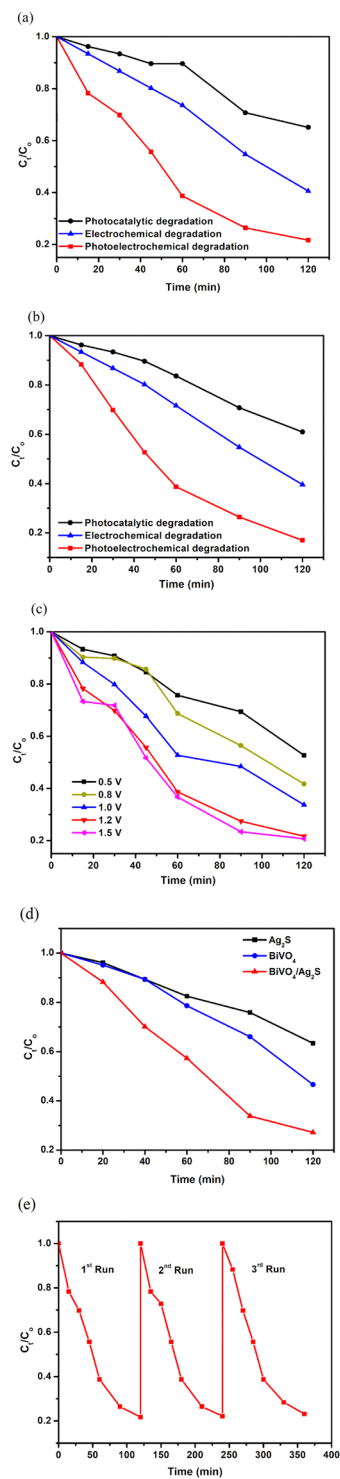


Figure 5. (a) Normalised concentration decay versus time plot for photocatalytic, electrocatalytic and photoelectrocatalytic degradation of (a) ciprofloxacin and (b) sulfamethoxazole using FTO-BiVO₄/Ag₂S electrode; (c) Effects of potential on degradation of ciprofloxacin; (d) Normalised concentration decay versus time plot for PEC degradation of ciprofloxacin on FTO-Ag₂S, FTO-BiVO₄, FTO-BiVO₄/Ag₂S electrodes; (e) Cycle experiments for the degradation of ciprofloxacin on FTO-BiVO₄/Ag₂S electrode.

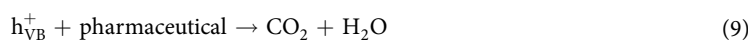
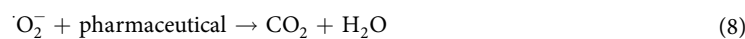
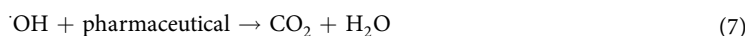
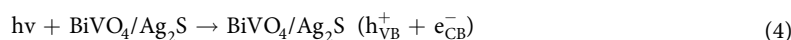
Applied bias potential is a critical parameter that affects photoelectrocatalytic degradation process. In order to evaluate the dependence of percentage removal of organics using the binary electrode on potential, the photoelectrocatalytic degradation was carried out with applied bias potential in the range of 0.2 V–1.5 V (Versus Ag/AgCl). It can be seen that the percentage degradation of ciprofloxacin increased with increase in applied bias potential with a value of about 10% stepwise up till potential of 1.2 V (Fig. 5c). The applied bias potential plays a major

role in separation electron – hole pair by driving the photogenerated electrons away from the anode towards the cathode. As shown in the result, the higher the applied potential, the higher the driving force for the electron. Therefore, the degradation increases because there was reduced recombination of photoinduced electron – hole pairs at higher potential. When higher potential of 1.5 V was applied, the difference in the percentage degradation with that obtained with 1.2 V was approximately 1% which was relatively insignificant when compared with the trend. This revealed that beyond the optimal potential, higher applied bias potential could yield insignificant improvement in the percentage degradation which could be due to side reaction of evolved oxygen at higher potential⁵⁵. Based on the result obtained, 1.2 V was selected as the optimal bias potential for the photoelectrocatalytic degradation of pharmaceuticals on the BiVO₄/Ag₂S electrode.

The improved charge separation in the binary electrode through the construction of p-n heterojunction was also confirmed by comparing its performance in the photoelectrocatalytic degradation of pharmaceuticals with that of the pristine electrodes of BiVO₄ and Ag₂S. As shown in Fig. 5d, BiVO₄ and Ag₂S electrodes gave a percentage removal of 63% and 50% respectively which were lower than 80% ciprofloxacin removal achieved on the BiVO₄/Ag₂S photoanode. The better performance of the binary electrode suggested that p-n heterojunction constructed facilitated the migration of electrons from the conduction band of Ag₂S to BiVO₄ while holes from BiVO₄ moves to the valence band of Ag₂S yielding enhanced photogenerated charge carriers separation resulting in better photoelectrocatalytic performance²⁸.

One of the advantages of photoelectrocatalytic degradation over convention photocatalysis is the ease of reusability of the material. The BiVO₄/Ag₂S electrode also showed impressive stability and reusability as seen from the cycling experiments (Fig. 5e). The results were obtained by using the same BiVO₄/Ag₂S three different times. After each cycle, the electrode was purged with deionized water and air dried at room temperature. After the third application the percentage removal of ciprofloxacin was approximately 79% suggesting that there was no remarkable change in the performance of the electrode after using it three times showing that the electrode is relatively stable and can be reused.

Proposed mechanism of degradation and scavenger studies. The degradation of organic molecules during photoelectrocatalytic processes happens when generated reactive species attack and oxidize the organic molecules. The photogenerated holes, hydroxyl and superoxide radicals usually play the predominant roles in photoelectrocatalytic degradation experiments. Equations 4–9 give the mechanism of formation of these reactive species and their oxidation reactions with the pharmaceutical molecules for total mineralization.



The contribution of individual reactive specie in the PEC degradation of the ciprofloxacin molecule was determined by trapping experiments which was conducted by inhibiting the effects of holes, hydroxyl radicals and superoxide radicals through the introductions of ethylenediaminetetraacetate salt (EDTA), t-butanol (t-BuOH) and p-benzoquinone (p-BZQ) respectively^{56,57} in the reaction medium. As seen in Fig. 6a, photogenerated holes play a crucial role in the breaking down of the pharmaceutical molecules since the percentage removal dropped to almost 10% when holes were masked through the addition of EDTA. The effect of hydroxyl radicals on the degradation of the pharmaceutical molecules cannot also be overlooked process because the degradation efficiency dropped to 52% with the addition of t-butanol. The hydroxyl radicals were produced in the reaction system through the oxidation reactions of water molecules by photogenerated holes. Unlike the holes and hydroxyl radicals, superoxide radicals performed a seemingly insignificant role in the oxidation of the pharmaceutical molecules because percentage removal of 76% was still achieved when the superoxide radicals were trapped by the addition of p-BZQ. Literatures have shown that hydroxyl radicals are not produced in detectable amount when BiVO₄ is illuminated due to rapid recombination because of rapid recombination with photogenerated electrons^{48,58}. But in this work, the fact that holes and hydroxyl radicals play predominant roles in the breaking down of the pharmaceuticals confirms that better charge separation can be achieved with BiVO₄ through the formation of heterojunction with Ag₂S.

The possible mechanism of the spontaneous mobility of photogenerated electron-hole pairs between the interface the two semiconductors is proposed by obtaining the relative band edge potential of the conduction band and valence band of both semiconductors using Eqs. 9 and 10.

$$E_{\text{CB}} = X - E_c - 0.5E_g \quad (10)$$

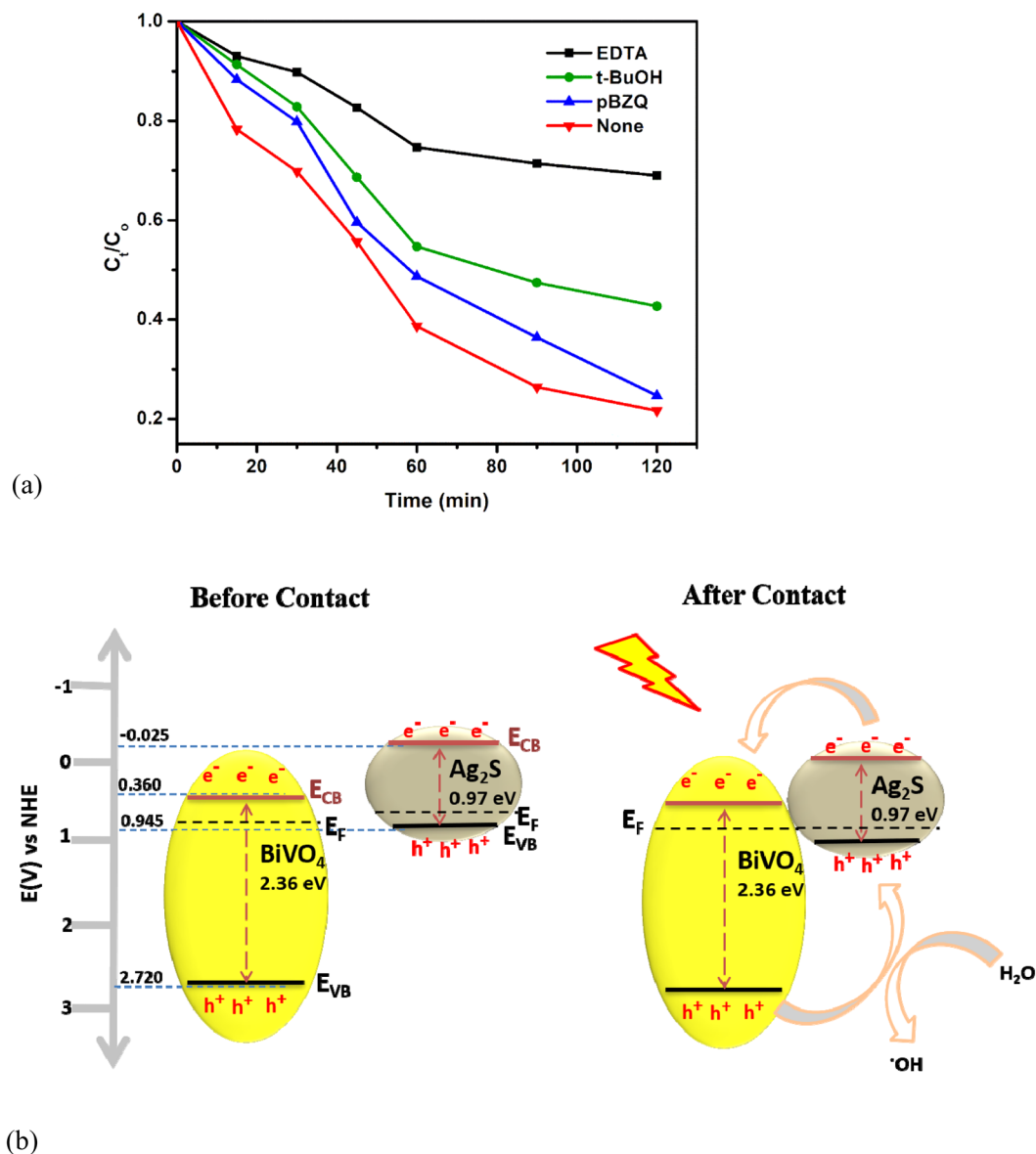


Figure 6. (a) Scavenger studies of the photoelectrocatalytic degradation of ciprofloxacin on FTO-BiVO₄/Ag₂S; (b) Band alignment between BiVO₄ and Ag₂S.

$$E_{VB} = E_g + E_{CB} \quad (11)$$

E_{VB} and E_{CB} stand for the valence and conduction band edge potentials respectively. X represent the electronegativity of the semiconductor usually calculated as the geometric mean of the absolute electronegativities of the constituent atoms in the semiconductor ($X = 6.04$ for BiVO₄ and 4.96 for Ag₂S). E_C is the energy of the free electrons on hydrogen scale which is approximately 4.50 eV (vs NHE). Energy band gap (E_g) has been estimated to be 2.36 eV for BiVO₄ and 0.97 eV for Ag₂S respectively using Tauc equation (Fig. 3b). Therefore, the E_{CB} and E_{VB} of BiVO₄ were calculated to be 0.360 eV and 2.720 eV respectively while for Ag₂S, the values obtained were -0.025 eV and 0.945 eV for E_{CB} and E_{VB} respectively. The values of E_{CB} and E_{VB} for Ag₂S are lower than the corresponding values for BiVO₄ indicating that the formation of type II heterojunction is possible when the two semiconductors aligned. As a p-type semiconductor, the Fermi energy level of Ag₂S is located slightly above the valence band while that of BiVO₄, n-type, is slightly below its conduction band. As shown in Fig. 6b, when the two semiconductors are in contact, the Fermi energy level aligned and internal electric field is established in such a way that the holes can be effectively separated into the valence band of Ag₂S and be available to oxidize directly the pharmaceutical molecules or produce hydroxyl radicals from water molecules while the electrons migrate to the conduction band of BiVO₄ in opposite direction of the internal electric field resulting in efficient charge separation²⁸. The electrons can also react with oxygen molecules to produced superoxide radicals⁵⁹ but the effect superoxide in the degradation process in this study is limited.

Conclusion

A photoanode of BiVO₄/Ag₂S with p-n heterojunction was successfully prepared through electrodeposition and successive ionic layer adsorption/reaction method on FTO glass. The construction of p-n heterojunction reduced the common problem of rapid recombination of photogenerated electron-hole pairs. This was confirmed through the photocurrent response of BiVO₄/Ag₂S (1.194 mA/cm⁻²) which was higher than both pristine BiVO₄ (0.802 mA/cm⁻²) and Ag₂S (0.165 mA/cm⁻²). When applied for the photoelectrocatalytic degradation of pharmaceuticals, the percentage removal of 80% and 86% were recorded for ciprofloxacin and sulfamethoxazole respectively. Overall, the reports from this research revealed that BiVO₄/Ag₂S electrode can be applied to oxidize recalcitrant pharmaceuticals in aqueous medium and pre-treated real pharmaceutical effluents and this can be achieved a reduced cost through the use of lower bias potential. In future works, enhancement of BiVO₄/Ag₂S performance for PEC water treatment will be studied using photoactive cathode.

Received: 10 December 2019; Accepted: 25 February 2020;

Published online: 24 March 2020

References

1. Yi, K. *et al.* Effect of ciprofloxacin on biological nitrogen and phosphorus removal from wastewater. *Sci. Total Environ.* **605–606**, 368–375 (2017).
2. Boudriche, L., Michael-Kordatou, I., Michael, S. & Karaolia, P. & Fatta-Kassinos, D. UV-C-driven oxidation of ciprofloxacin in conventionally treated urban wastewater: degradation kinetics, ecotoxicity and phytotoxicity assessment and inactivation of ciprofloxacin-resistant *Escherichia coli*. *J. Chem. Technol. Biotechnol.* **92**, 1380–1388 (2017).
3. Deegan, A. M. *et al.* Treatment options for wastewater effluents from pharmaceutical companies. *Int. J. Environ. Sci. Technol.* **8**, 649–666 (2011).
4. Peng, K. *et al.* MoS₂ nanosheets supported on carbon hybridized montmorillonite as an efficient heterogeneous catalyst in aqueous phase. *Appl. Clay Sci.* **183**, 105346 (2019).
5. Kuang, P. Y. *et al.* Enhanced Photoelectrocatalytic Activity of BiOI Nanoplate-Zinc Oxide Nanorod p-n Heterojunction. *Chem. - Eur. J.* **21**, 15360–15368 (2015).
6. Peleyeju, M. G. & Arotiba, O. A. Recent trend in visible-light photoelectrocatalytic systems for degradation of organic contaminants in water/wastewater. *Environ. Sci. Water Res. Technol.* **4**, 1389–1411 (2018).
7. Garcia-Segura, S. & Brillas, E. Applied photoelectrocatalysis on the degradation of organic pollutants in wastewaters. *J. Photochem. Photobiol. C Photochem. Rev.* **31**, 1–35 (2017).
8. Peleyeju, M. G. *et al.* Photoelectrocatalytic water treatment systems: Degradation, kinetics and intermediate products studies of sulfamethoxazole on a TiO₂-exfoliated graphite electrode. *RSC Adv.* **7**, 40571–40580 (2017).
9. Daghrir, R., Drogui, P., Ka, I. & El Khakani, M. A. Photoelectrocatalytic degradation of chlortetracycline using Ti/TiO₂ nanostructured electrodes deposited by means of a Pulsed Laser Deposition process. *J. Hazard. Mater.* **199–200**, 15–24 (2012).
10. Ntsendwana, B., Sampath, S., Mamba, B. B., Oluwafemi, O. S. & Arotiba, O. A. Photoelectrochemical degradation of eosin yellowish dye on exfoliated graphite-ZnO nanocomposite electrode. *J. Mater. Sci. Mater. Electron.* **27**, 592–598 (2016).
11. Wang, Y. *et al.* Enhancement mechanism of fiddlehead-shaped TiO₂-BiVO₄ type II heterojunction in SPEC towards RhB degradation and detoxification. *Appl. Surf. Sci.* **463**, 234–243 (2019).
12. Tang, W., Wang, Q., Zeng, X. & Chen, X. Photocatalytic degradation on Disperse Blue with modified nano-TiO₂ film electrode. *J. Solid State Electrochem.* **16**, 1429–1445 (2012).
13. Umukoro, E. H., Peleyeju, M. G., Ngila, J. C. & Arotiba, O. A. Towards wastewater treatment: Photo-assisted electrochemical degradation of 2-nitrophenol and orange II dye at a tungsten trioxide-exfoliated graphite composite electrode. *Chem. Eng. J.* **317**, 290–301 (2017).
14. Su, Z. *et al.* Rapid mass production of novel 3D Cu@CuI core-shell mesh as highly flexible and efficient photocatalyst. *J. Am. Ceram. Soc.* **101**, 5781–5790 (2018).
15. Chemelewski, W. D., Mabayoje, O. & Mullins, C. B. SILAR Growth of Ag₃VO₄ and Characterization for Photoelectrochemical Water Oxidation. *J. Phys. Chem. C.* **119**, 26803–26808 (2015).
16. Wang, W. *et al.* Preparation of p-n junction Cu₂O/BiVO₄ heterogeneous nanostructures with enhanced visible-light photocatalytic activity. *Appl. Catal. B. Environ.* **134–135**, 293–301 (2013).
17. Sinclair, T. S., Gray, H. B. & Müller, A. M. Photoelectrochemical Performance of BiVO₄ Photoanodes Integrated with [NiFe]-Layered Double Hydroxide Nanocatalysts. *Eur. J. Inorg. Chem.* **2018**, 1060–1067 (2018).
18. Dong, L. *et al.* Sunlight responsive BiVO₄ photocatalyst: Effects of pH on L-cysteine-assisted hydrothermal treatment and enhanced degradation of ofloxacin. *Catal. Commun.* **16**, 250–254 (2011).
19. Li, J., Zhou, J., Hao, H. & Li, W. Controlled synthesis of Fe₂O₃ modified Ag-010BiVO₄ heterostructures with enhanced photoelectrochemical activity toward the dye degradation. *Appl. Surf. Sci.* **399**, 1–9 (2017).
20. Ma, Q. *et al.* Construction of CuS/TiO₂ nano-tube arrays photoelectrode and its enhanced visible light photoelectrocatalytic decomposition and mechanism of penicillin G. *Electrochim. Acta* **283**, 1154–1162 (2018).
21. Bi, Y., Ouyang, S., Umezawa, N., Cao, J. & Ye, J. Facet effect of single-crystalline Ag₃PO₄ sub-microcrystals on photocatalytic properties. *J. Am. Chem. Soc.* **133**, 6490–6492 (2011).
22. Peng, K. *et al.* Emerging WS₂/montmorillonite composite nanosheets as an efficient hydrophilic photocatalyst for aqueous phase reactions. *Sci. Rep.* **9**, 1–9 (2019).
23. Mahzoon, S., Nowee, S. M. & Haghighi, M. Synergetic combination of 1D-2D g-C₃N₄ heterojunction nanophotocatalyst for hydrogen production via water splitting under visible light irradiation. *Renew. Energy* **127**, 433–443 (2018).
24. Wang, W.-K. *et al.* Two-dimensional TiO₂-g-C₃N₄ with both Ti-N and C-O bridges with excellent conductivity for synergistic photoelectrocatalytic degradation of bisphenol A. *J. Colloid Interface Sci.* **557**, 227–235 (2019).
25. Xia, L. *et al.* BiVO₄ Photoanode with Exposed (040) Facets for Enhanced Photoelectrochemical Performance. *Nano-Micro Lett.* **10**, 11 (2018).
26. Tan, H. L., Amal, R. & Ng, Y. H. Alternative strategies in improving the photocatalytic and photoelectrochemical activities of visible light-driven BiVO₄: A review. *J. Mater. Chem. A* **5**, 16498–16521 (2017).
27. Zhao, X. *et al.* One-step fabrication of carbon decorated Co₃O₄/BiVO₄ p-n heterostructure for enhanced visible-light photocatalytic properties. *Chem. Phys. Lett.* **706**, 440–447 (2018).
28. Zhang, L. & Jaroniec, M. Toward designing semiconductor-semiconductor heterojunctions for photocatalytic applications. *Appl. Surf. Sci.* **430**, 2–17 (2018).
29. Soltani, T., Tayyebi, A. & Lee, B. K. BiFeO₃/BiVO₄ p-n heterojunction for efficient and stable photocatalytic and photoelectrochemical water splitting under visible-light irradiation. *Catal. Today* **340**, 188–196 (2020).
30. Bai, S. *et al.* Two-step electrodeposition to fabricate the p-n heterojunction of a Cu₂O/BiVO₄ photoanode for the enhancement of photoelectrochemical water splitting. *Dalt. Trans.* **47**, 6763–6771 (2018).

31. Orimolade, B. O. *et al.* Solar photoelectrocatalytic degradation of ciprofloxacin at a FTO/BiVO₄/MnO₂ anode: Kinetics, intermediate products and degradation pathway studies. *J. Environ. Chem. Eng.* **8** (2020).
32. Lu, G. *et al.* *In situ* fabrication of BiVO₄-CeVO₄ heterojunction for excellent visible light photocatalytic degradation of levofloxacin. *J. Alloys Compd.* **772**, 122–131 (2019).
33. Zeng, Q. *et al.* Synthesis of WO₃/BiVO₄ photoanode using a reaction of bismuth nitrate with peroxovanadate on WO₃ film for efficient photoelectrocatalytic water splitting and organic pollutant degradation. *Appl. Catal. B Environ.* **217**, 21–29 (2017).
34. Li, L. P., Liu, M. & Zhang, W. De. Electrodeposition of CdS onto BiVO₄ films with high photoelectrochemical performance. *J. Solid State Electrochem.* **22**, 2569–2577 (2018).
35. Bai, S. *et al.* Fabricating of Fe₃O₄/BiVO₄ heterojunction based photoanode modified with NiFe-LDH nanosheets for efficient solar water splitting. *Chem. Eng. J.* **350**, 148–156 (2018).
36. Orimolade, B. O. *et al.* Interrogating solar photoelectrocatalysis on an exfoliated graphite–BiVO₄/ZnO composite electrode towards water treatment. *RSC Adv.* **9**, 16586–16595 (2019).
37. Huang, Q. *et al.* p-Type NiO modified BiVO₄ photoanodes with enhanced charge separation and solar water oxidation kinetics. *Mater. Lett.* **249**, 128–131 (2019).
38. Xiang, Z., Wang, Y., Yang, Z. & Zhang, D. Heterojunctions of β-AgVO₃/BiVO₄ composites for enhanced visible-light-driven photocatalytic antibacterial activity. *J. Alloys Compd.* **776**, 266–275 (2019).
39. Cao, D., Wang, Y., Qiao, M. & Zhao, X. Enhanced photoelectrocatalytic degradation of norfloxacin by an Ag₃PO₄/BiVO₄ electrode with low bias. *J. Catal.* **360**, 240–249 (2018).
40. Hu, H. *et al.* *In situ* formation of small-scale Ag₂S nanoparticles in carbonaceous aerogel for enhanced photodegradation performance. *J. Mol. Liq.* **292**, 111476 (2019).
41. Wei, Z. *et al.* Novel p-n heterojunction photocatalyst fabricated by flower-like BiVO₄ and Ag₂S nanoparticles: Simple synthesis and excellent photocatalytic performance. *Chem. Eng. J.* **361**, 1173–1181 (2019).
42. Guan, P. *et al.* Boosting Water Splitting Performance of BiVO₄ Photoanode through Selective Surface Decoration of Ag₂S. *ChemCatChem* **10**, 4941–4947 (2018).
43. Orimolade, B. O., Koiki, B. A., Peleyeju, G. M. & Arotiba, O. A. Visible light driven photoelectrocatalysis on a FTO/BiVO₄/BiOI anode for water treatment involving emerging pharmaceutical pollutants. *Electrochim. Acta* **307**, 285–292 (2019).
44. Zhang, K. *et al.* Co–Pd/BiVO₄: High-performance photocatalysts for the degradation of phenol under visible light irradiation. *Appl. Catal. B Environ.* **224**, 350–359 (2018).
45. Zhang, S., Wang, J., Chen, S., Li, R. & Peng, T. Construction of Ag₂S/WO₃ Direct Z-Scheme Photocatalyst for Enhanced Charge Separation Efficiency and H₂ Generation Activity. *Ind. Eng. Chem. Res.* **58**, 14802–14813 (2019).
46. Li, X. *et al.* Fabricated rGO-modified Ag₂S nanoparticles/g-C₃N₄ nanosheets photocatalyst for enhancing photocatalytic activity. *J. Colloid Interface Sci.* **554**, 468–478 (2019).
47. Ju, P., Wang, Y., Sun, Y. & Zhang, D. Controllable one-pot synthesis of a nest-like Bi₂WO₆/BiVO₄ composite with enhanced photocatalytic antifouling performance under visible light irradiation. *Dalt. Trans.* **45**, 4588–4602 (2016).
48. Yan, M. *et al.* Synthesis and Characterization of Novel BiVO₄/Ag₃VO₄ Heterojunction with Enhanced Visible-Light-Driven Photocatalytic Degradation of Dyes. *ACS Sustain. Chem. Eng.* **4**, 757–766 (2016).
49. Zamiri, R. *et al.* The structural and optical constants of Ag₂S semiconductor nanostructure in the Far-Infrared. *Chem. Cent. J.* **9**, 4–9 (2015).
50. Wang, D., Shen, H., Guo, L., Fu, F. & Liang, Y. Design and construction of the sandwich-like Z-scheme multicomponent CdS/Ag/Bi₂MoO₆ heterostructure with enhanced photocatalytic performance in RhB photodegradation. *New J. Chem.* **40**, 8614–8624 (2016).
51. Feng, J., Cheng, L., Zhang, J., Okoth, O. K. & Chen, F. Preparation of BiVO₄/ZnO composite film with enhanced visible-light photoelectrocatalytic activity. *Ceram. Int.* **44**, 3672–3677 (2018).
52. Tang, X., Wang, Y. & Cao, G. Effect of the adsorbed concentration of dye on charge recombination in dye-sensitized solar cells. *J. Electroanal. Chem.* **694**, 6–11 (2013).
53. Li, L. *et al.* Photocurrent enhanced dye-sensitized solar cells based on TiO₂ loaded K₆SiW₁₁O₃₉Co(ii)(H₂O)·xH₂O photoanode materials. *Dalt. Trans.* **43**, 1577–1582 (2014).
54. Bai, S. *et al.* Two-step electrodeposition to fabricate the p–n heterojunction of a Cu₂O/BiVO₄ photoanode for the enhancement of photoelectrochemical water splitting. *Dalt. Trans.* **47**, 6763–6771 (2018).
55. Qiu, L. *et al.* Construction of Ag₃PO₄/Ag₄P₂O₇ nanospheres sensitized hierarchical titanium dioxide nanotube mesh for photoelectrocatalytic degradation of methylene blue. *Sep. Purif. Technol.* **215**, 619–624 (2019).
56. Medel, A., Ramírez, J. A., Cárdenas, J., Sirés, I. & Meas, Y. Evaluating the electrochemical and photoelectrochemical production of hydroxyl radical during electrocoagulation process. *Sep. Purif. Technol.* **208**, 59–67 (2019).
57. Akbarzadeh, R., Fung, C. S. L., Rather, R. A. & Lo, I. M. C. One-pot hydrothermal synthesis of g-C₃N₄/Ag/AgCl/BiVO₄ micro-flower composite for the visible light degradation of ibuprofen. *Chem. Eng. J.* **341**, 248–261 (2018).
58. Trzciński, K., Szkoda, M., Sawczak, M., Karczewski, J. & Lisowska-Oleksiak, A. Visible light activity of pulsed layer deposited BiVO₄/MnO₂ films decorated with gold nanoparticles: The evidence for hydroxyl radicals formation. *Appl. Surf. Sci.* **385**, 199–208 (2016).
59. Peng, K. *et al.* One-step hydrothermal growth of MoS₂ nanosheets/CdS nanoparticles heterostructures on montmorillonite for enhanced visible light photocatalytic activity. *Appl. Clay Sci.* **175**, 86–93 (2019).

Acknowledgements

Financial supports from the following institutions in South Africa are gratefully acknowledged: The National Research Foundation (CPRR Grant number: 118546); Water Research Commission (Grant Number: K5/2567); Centre for Nanomaterials Science Research, University of Johannesburg; Faculty of Science, University of Johannesburg; Global Excellence and Stature (GES) doctoral support, University of Johannesburg; B.O.O. is grateful to University of Ilorin, Nigeria for study leave.

Author contributions

Benjamin O. Orimolade: Conceptualization, Methodology, Investigation, Writing - Original Draft Omotayo A. Arotiba: Conceptualization, Writing - Review & Editing, Supervision, Funding acquisition, Resources.

Competing interests

The authors declare no competing interests.

Additional information

Supplementary information is available for this paper at <https://doi.org/10.1038/s41598-020-62425-w>.

Correspondence and requests for materials should be addressed to O.A.A.

Reprints and permissions information is available at www.nature.com/reprints.

Publisher's note Springer Nature remains neutral with regard to jurisdictional claims in published maps and institutional affiliations.



Open Access This article is licensed under a Creative Commons Attribution 4.0 International License, which permits use, sharing, adaptation, distribution and reproduction in any medium or format, as long as you give appropriate credit to the original author(s) and the source, provide a link to the Creative Commons license, and indicate if changes were made. The images or other third party material in this article are included in the article's Creative Commons license, unless indicated otherwise in a credit line to the material. If material is not included in the article's Creative Commons license and your intended use is not permitted by statutory regulation or exceeds the permitted use, you will need to obtain permission directly from the copyright holder. To view a copy of this license, visit <http://creativecommons.org/licenses/by/4.0/>.

© The Author(s) 2020